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# **Chapter 5**

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**Large and Fast:  
Exploiting Memory  
Hierarchy**

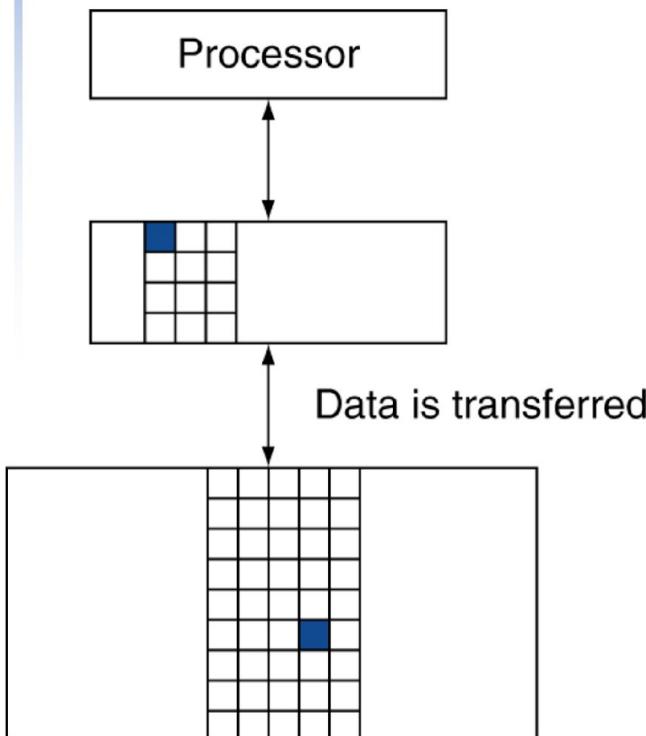
# Principle of Locality

- Programs access a small proportion of their address space at any time
- Temporal locality
  - Items accessed recently are likely to be accessed again soon
    - e.g., instructions in a loop, induction variables
- Spatial locality
  - Items near those accessed recently are likely to be accessed soon
    - E.g., sequential instruction access, array data

# Taking Advantage of Locality

- Memory hierarchy
- Store everything on disk
- Copy recently accessed (and nearby) items from disk to smaller DRAM memory
  - Main memory
- Copy more recently accessed (and nearby) items from DRAM to smaller SRAM memory
  - Cache memory attached to CPU

# Memory Hierarchy Levels



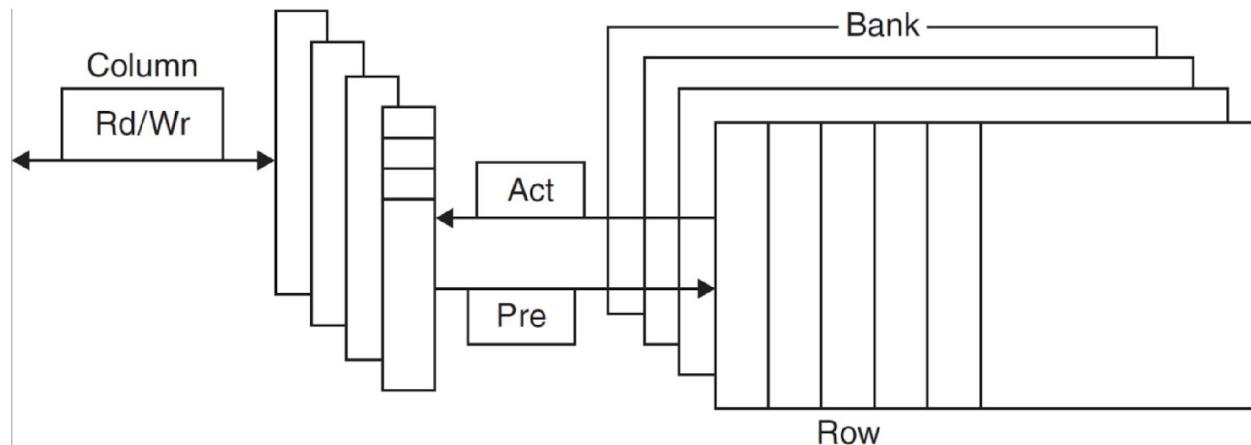
- Block (aka line): unit of copying
  - May be multiple words
- If accessed data is present in upper level
  - Hit: access satisfied by upper level
    - Hit ratio: hits/accesses
- If accessed data is absent
  - Miss: block copied from lower level
    - Time taken: miss penalty
    - Miss ratio: misses/accesses  
= 1 – hit ratio
  - Then accessed data supplied from upper level

# Memory Technology

- Static RAM (SRAM)
  - 0.5ns – 2.5ns, \$2000 – \$5000 per GB
- Dynamic RAM (DRAM)
  - 50ns – 70ns, \$20 – \$75 per GB
- Magnetic disk
  - 5ms – 20ms, \$0.20 – \$2 per GB
- Ideal memory
  - Access time of SRAM
  - Capacity and cost/GB of disk

# DRAM Technology

- Data stored as a charge in a capacitor
  - Single transistor used to access the charge
  - Must periodically be refreshed
    - Read contents and write back
    - Performed on a DRAM “row”

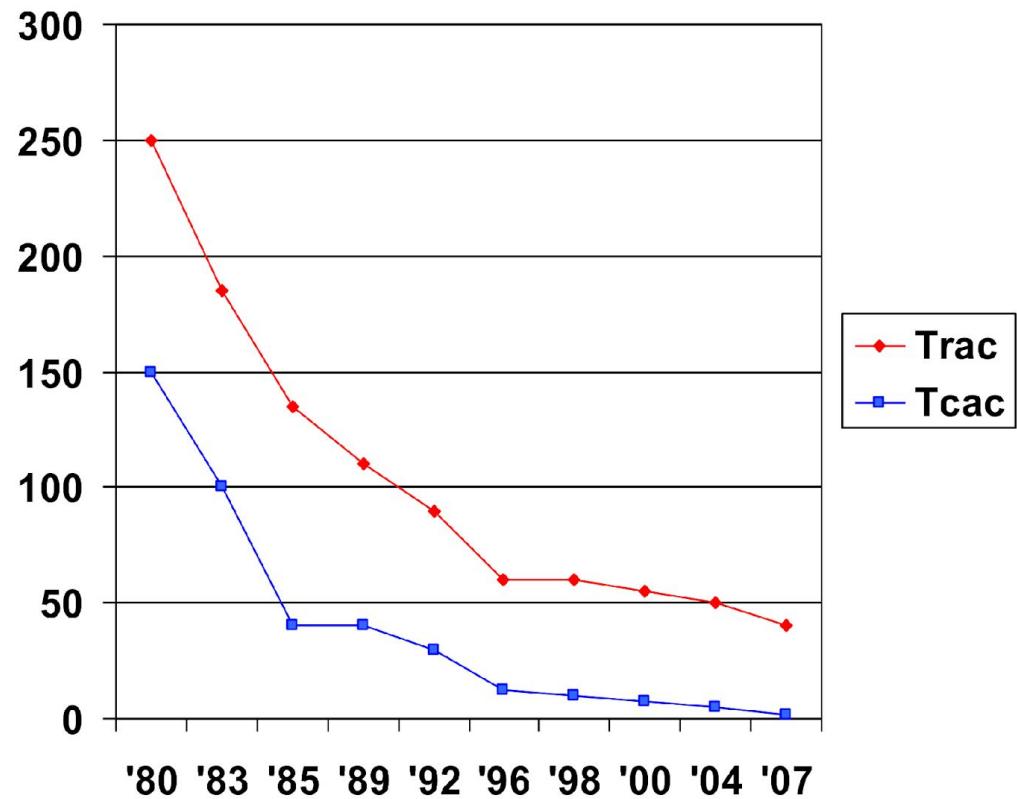


# Advanced DRAM Organization

- Bits in a DRAM are organized as a rectangular array
  - DRAM accesses an entire row
  - Burst mode: supply successive words from a row with reduced latency
- Double data rate (DDR) DRAM
  - Transfer on rising and falling clock edges
- Quad data rate (QDR) DRAM
  - Separate DDR inputs and outputs

# DRAM Generations

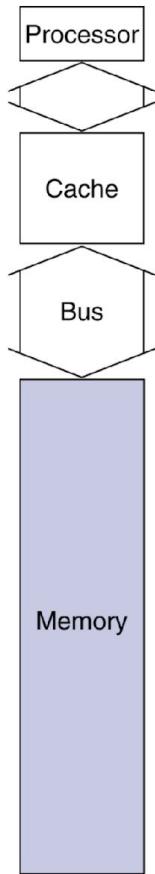
Year	Capacity	\$/GB
1980	64Kbit	\$1500000
1983	256Kbit	\$500000
1985	1Mbit	\$200000
1989	4Mbit	\$50000
1992	16Mbit	\$15000
1996	64Mbit	\$10000
1998	128Mbit	\$4000
2000	256Mbit	\$1000
2004	512Mbit	\$250
2007	1Gbit	\$50



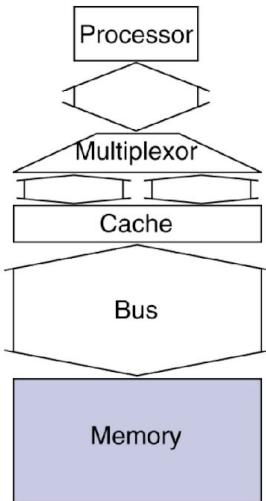
# DRAM Performance Factors

- Row buffer
  - Allows several words to be read and refreshed in parallel
- Synchronous DRAM
  - Allows for consecutive accesses in bursts without needing to send each address
  - Improves bandwidth
- DRAM banking
  - Allows simultaneous access to multiple DRAMs
  - Improves bandwidth

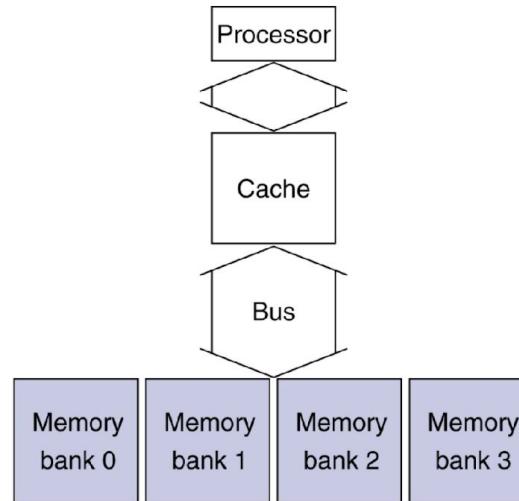
# Increasing Memory Bandwidth



a. One-word-wide  
memory organization



b. Wider memory organization

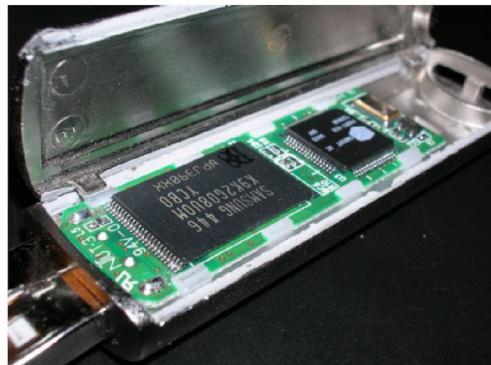


c. Interleaved memory organization

- **4-word wide memory**
  - Miss penalty =  $1 + 15 + 1 = 17$  bus cycles
  - Bandwidth =  $16 \text{ bytes} / 17 \text{ cycles} = 0.94 \text{ B/cycle}$
- **4-bank interleaved memory**
  - Miss penalty =  $1 + 15 + 4 \times 1 = 20$  bus cycles
  - Bandwidth =  $16 \text{ bytes} / 20 \text{ cycles} = 0.8 \text{ B/cycle}$

# Flash Storage

- Nonvolatile semiconductor storage
  - 100× – 1000× faster than disk
  - Smaller, lower power, more robust
  - But more \$/GB (between disk and DRAM)

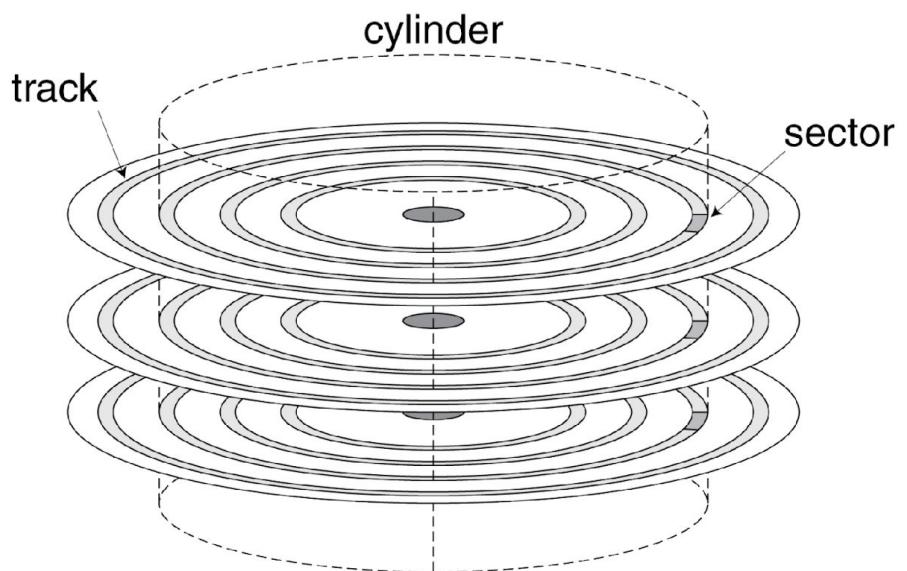


# Flash Types

- NOR flash: bit cell like a NOR gate
  - Random read/write access
  - Used for instruction memory in embedded systems
- NAND flash: bit cell like a NAND gate
  - Denser (bits/area), but block-at-a-time access
  - Cheaper per GB
  - Used for USB keys, media storage, ...
- Flash bits wears out after 1000's of accesses
  - Not suitable for direct RAM or disk replacement
  - Wear leveling: remap data to less used blocks

# Disk Storage

- Nonvolatile, rotating magnetic storage



# Disk Sectors and Access

- Each sector records
  - Sector ID
  - Data (512 bytes, 4096 bytes proposed)
  - Error correcting code (ECC)
    - Used to hide defects and recording errors
  - Synchronization fields and gaps
- Access to a sector involves
  - Queuing delay if other accesses are pending
  - Seek: move the heads
  - Rotational latency
  - Data transfer
  - Controller overhead

# Disk Access Example

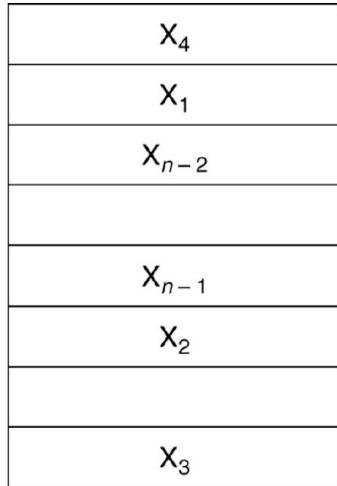
- Given
  - 512B sector, 15,000rpm, 4ms average seek time, 100MB/s transfer rate, 0.2ms controller overhead, idle disk
- Average read time
  - 4ms seek time
    - +  $\frac{1}{2} / (15,000/60) = 2\text{ms}$  rotational latency
    - +  $512 / 100\text{MB/s} = 0.005\text{ms}$  transfer time
    - + 0.2ms controller delay
    - = 6.2ms
- If actual average seek time is 1ms
  - Average read time = 3.2ms

# Disk Performance Issues

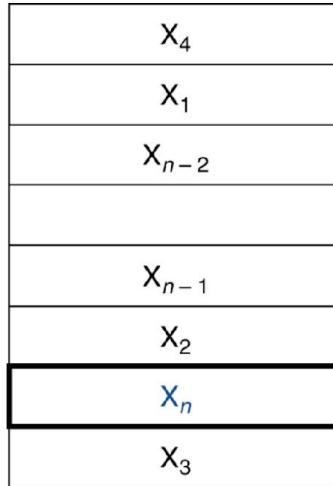
- Manufacturers quote average seek time
  - Based on all possible seeks
  - Locality and OS scheduling lead to smaller actual average seek times
- Smart disk controller allocate physical sectors on disk
  - Present logical sector interface to host
  - SCSI, ATA, SATA
- Disk drives include caches
  - Prefetch sectors in anticipation of access
  - Avoid seek and rotational delay

# Cache Memory

- Cache memory
  - The level of the memory hierarchy closest to the CPU
- Given accesses  $X_1, \dots, X_{n-1}, X_n$



a. Before the reference to  $X_n$

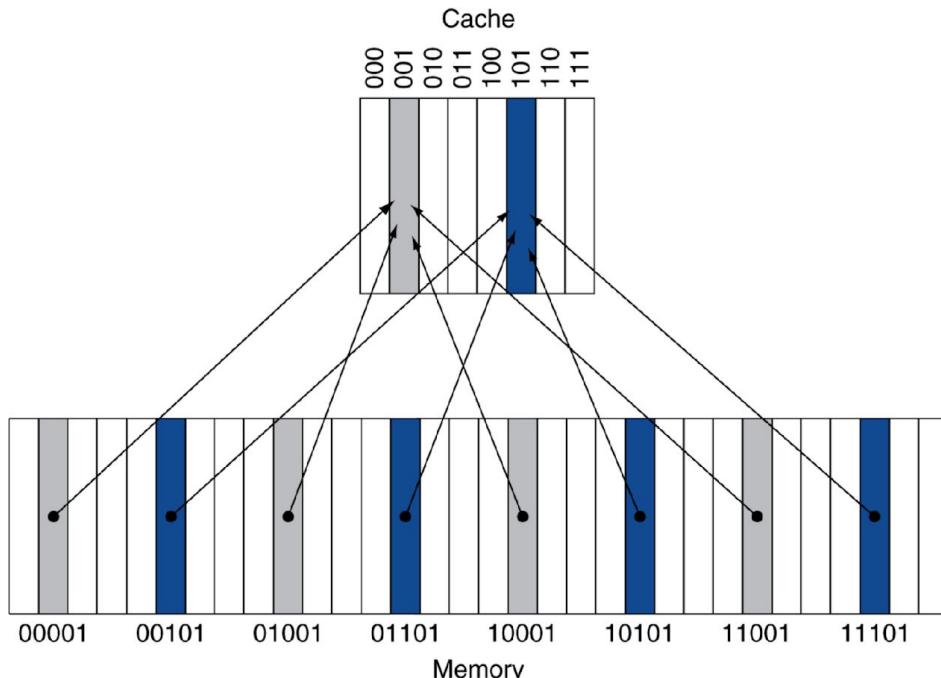


b. After the reference to  $X_n$

- How do we know if the data is present?
- Where do we look?

# Direct Mapped Cache

- Location determined by address
- Direct mapped: only one choice
  - (Block address) modulo (#Blocks in cache)



- #Blocks is a power of 2
- Use low-order address bits

# Tags and Valid Bits

- How do we know which particular block is stored in a cache location?
  - Store block address as well as the data
  - Actually, only need the high-order bits
  - Called the tag
- What if there is no data in a location?
  - Valid bit: 1 = present, 0 = not present
  - Initially 0

# Cache Example

- 8-blocks, 1 word/block, direct mapped
- Initial state

Index	V	Tag	Data
000	N		
001	N		
010	N		
011	N		
100	N		
101	N		
110	N		
111	N		

# Cache Example

Word addr	Binary addr	Hit/miss	Cache block
22	10 110	Miss	110

Index	V	Tag	Data
000	N		
001	N		
010	N		
011	N		
100	N		
101	N		
110	Y	10	Mem[10110]
111	N		

# Cache Example

Word addr	Binary addr	Hit/miss	Cache block
26	11 010	Miss	010

Index	V	Tag	Data
000	N		
001	N		
010	Y	11	Mem[11010]
011	N		
100	N		
101	N		
110	Y	10	Mem[10110]
111	N		

# Cache Example

Word addr	Binary addr	Hit/miss	Cache block
22	10 110	Hit	110
26	11 010	Hit	010

Index	V	Tag	Data
000	N		
001	N		
010	Y	11	Mem[11010]
011	N		
100	N		
101	N		
110	Y	10	Mem[10110]
111	N		

# Cache Example

Word addr	Binary addr	Hit/miss	Cache block
16	10 000	Miss	000
3	00 011	Miss	011
16	10 000	Hit	000

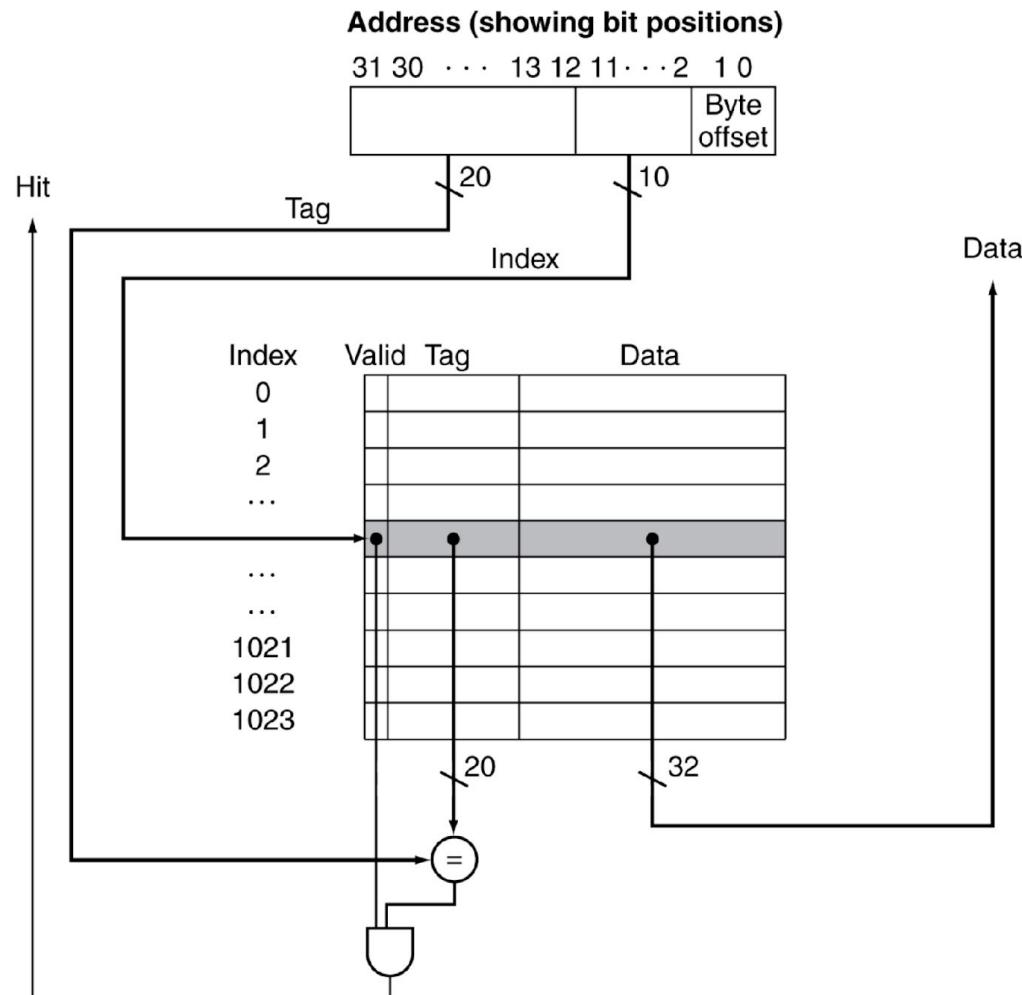
Index	V	Tag	Data
000	Y	10	Mem[10000]
001	N		
010	Y	11	Mem[11010]
011	Y	00	Mem[00011]
100	N		
101	N		
110	Y	10	Mem[10110]
111	N		

# Cache Example

Word addr	Binary addr	Hit/miss	Cache block
18	10 010	Miss	010

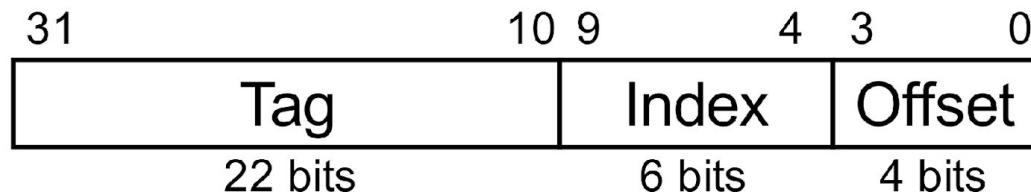
Index	V	Tag	Data
000	Y	10	Mem[10000]
001	N		
<b>010</b>	<b>Y</b>	<b>10</b>	<b>Mem[10010]</b>
011	Y	00	Mem[00011]
100	N		
101	N		
110	Y	10	Mem[10110]
111	N		

# Address Subdivision



# Example: Larger Block Size

- 64 blocks, 16 bytes/block
  - To what block number does address 1200 map?
- Block address =  $1200/16 = 75$
- Block number =  $75 \text{ modulo } 64 = 11$



# Block Size Considerations

- Larger blocks should reduce miss rate
  - Due to spatial locality
- But in a fixed-sized cache
  - Larger blocks  fewer of them
    - More competition  increased miss rate
  - Larger blocks  pollution
- Larger miss penalty
  - Can override benefit of reduced miss rate
  - Early restart and critical-word-first can help

# Cache Misses

- On cache hit, CPU proceeds normally
- On cache miss
  - Stall the CPU pipeline
  - Fetch block from next level of hierarchy
  - Instruction cache miss
    - Restart instruction fetch
  - Data cache miss
    - Complete data access

# Write-Through

- On data-write hit, could just update the block in cache
  - But then cache and memory would be inconsistent
- Write through: also update memory
- But makes writes take longer
  - e.g., if base CPI = 1, 10% of instructions are stores, write to memory takes 100 cycles
    - Effective CPI =  $1 + 0.1 \times 100 = 11$
- Solution: write buffer
  - Holds data waiting to be written to memory
  - CPU continues immediately
    - Only stalls on write if write buffer is already full

# Write-Back

- Alternative: On data-write hit, just update the block in cache
  - Keep track of whether each block is dirty
- When a dirty block is replaced
  - Write it back to memory
  - Can use a write buffer to allow replacing block to be read first

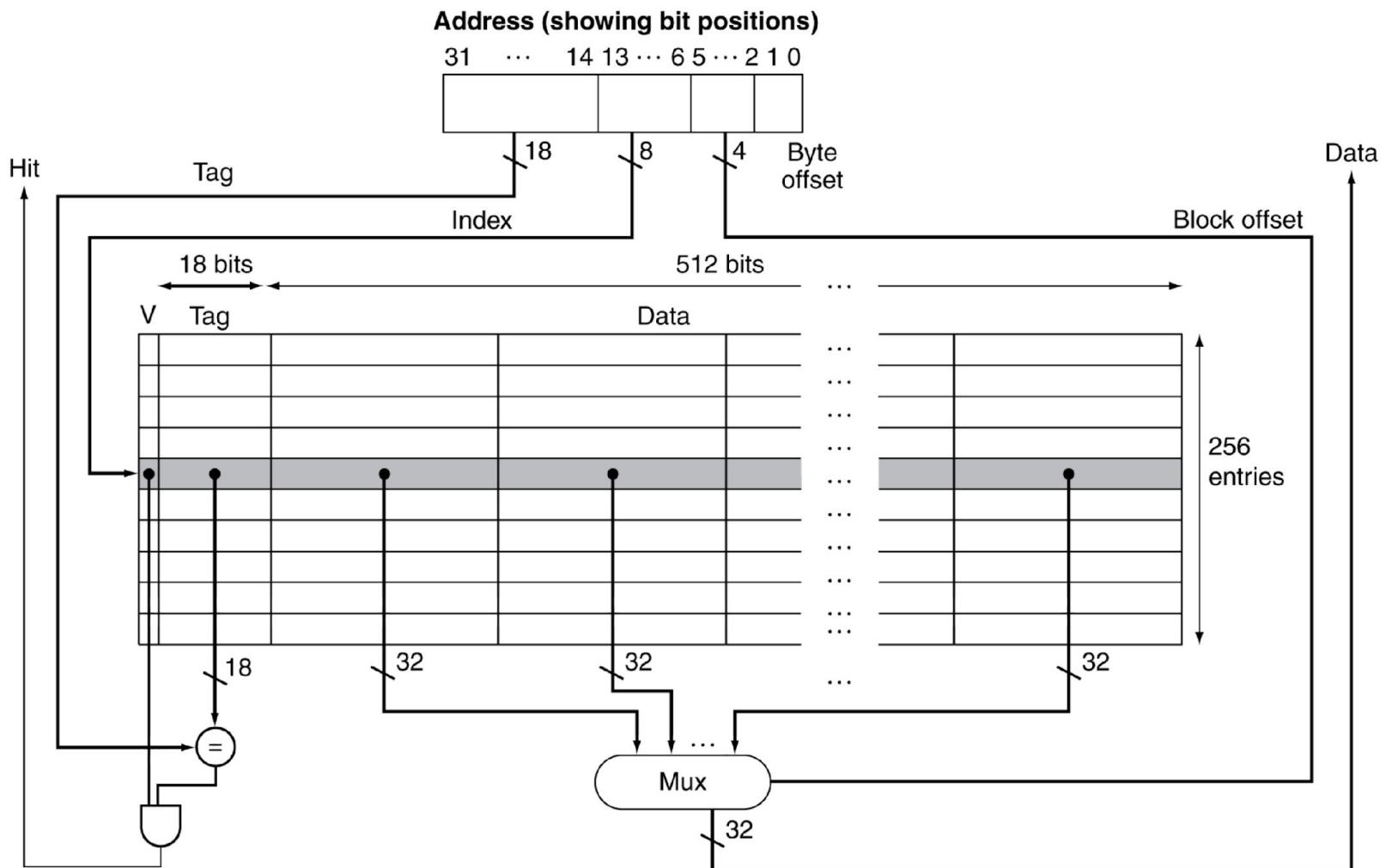
# Write Allocation

- What should happen on a write miss?
- Alternatives for write-through
  - Allocate on miss: fetch the block
  - Write around: don't fetch the block
    - Since programs often write a whole block before reading it (e.g., initialization)
- For write-back
  - Usually fetch the block

# Example: Intrinsity FastMATH

- Embedded MIPS processor
  - 12-stage pipeline
  - Instruction and data access on each cycle
- Split cache: separate I-cache and D-cache
  - Each 16KB: 256 blocks × 16 words/block
  - D-cache: write-through or write-back
- SPEC2000 miss rates
  - I-cache: 0.4%
  - D-cache: 11.4%
  - Weighted average: 3.2%

# Example: Intrinsity FastMATH



# Main Memory Supporting Caches

- Use DRAMs for main memory
  - Fixed width (e.g., 1 word)
  - Connected by fixed-width clocked bus
    - Bus clock is typically slower than CPU clock
- Example cache block read
  - 1 bus cycle for address transfer
  - 15 bus cycles per DRAM access
  - 1 bus cycle per data transfer
- For 4-word block, 1-word-wide DRAM
  - Miss penalty =  $1 + 4 \times 15 + 4 \times 1 = 65$  bus cycles
  - Bandwidth =  $16 \text{ bytes} / 65 \text{ cycles} = 0.25 \text{ B/cycle}$

# Measuring Cache Performance

- Components of CPU time
  - Program execution cycles
    - Includes cache hit time
  - Memory stall cycles
    - Mainly from cache misses
- With simplifying assumptions:

Memory stall cycles

$$= \frac{\text{Memory accesses}}{\text{Program}} \times \text{Miss rate} \times \text{Miss penalty}$$

$$= \frac{\text{Instructions}}{\text{Program}} \times \frac{\text{Misses}}{\text{Instruction}} \times \text{Miss penalty}$$

# Cache Performance Example

- Given
  - I-cache miss rate = 2%
  - D-cache miss rate = 4%
  - Miss penalty = 100 cycles
  - Base CPI (ideal cache) = 2
  - Load & stores are 36% of instructions
- Miss cycles per instruction
  - I-cache:  $0.02 \times 100 = 2$
  - D-cache:  $0.36 \times 0.04 \times 100 = 1.44$
- Actual CPI =  $2 + 2 + 1.44 = 5.44$ 
  - Ideal CPU is  $5.44/2 = 2.72$  times faster

# Average Access Time

- Hit time is also important for performance
- Average memory access time (AMAT)
  - $AMAT = \text{Hit time} + \text{Miss rate} \times \text{Miss penalty}$
- Example
  - CPU with 1ns clock, hit time = 1 cycle, miss penalty = 20 cycles, I-cache miss rate = 5%
  - $AMAT = 1 + 0.05 \times 20 = 2\text{ns}$ 
    - 2 cycles per instruction

# Performance Summary

- When CPU performance increased
  - Miss penalty becomes more significant
- Decreasing base CPI
  - Greater proportion of time spent on memory stalls
- Increasing clock rate
  - Memory stalls account for more CPU cycles
- Can't neglect cache behavior when evaluating system performance